

UT54BS16245 16bit Bus Switch

Preliminary Datasheet

February 2015

www.aeroflex.com/busswitch



FEATURES

- Provides cold-sparing capability without the need for actual cold-sparing multiplexer inputs
- Bidirectional operation
- 3.3V operating lower supply with typical 11Ω switch connection between ports
- 5V operating lower supply with typical 5Ω switch connection between ports
- Isolates non cold-spared devices from an active bus
- Ultra low power CMOS technology
- ESD rating HBM: 2000V, Class 2
- Operational environment:
 - Total dose: 300 krad(Si)
 - Latchup immune (LET <= 100 MeV-cm2/mg)
- Packaging:
 - 48-lead flatpack
- Standard Microcircuit Drawing (SMD)
 - QML Q and V pending

INTRODUCTION

The UT54BS16245 provides 16 bits of high-speed CMOS-compatible bus switching in a standard '16245 device pinout. The low on-state resistance of the switch allows connections to be made with minimal propagation delay. The device is organized as two 8-bit low-impedance switches with separate output-enable (/EN) inputs. When OE is low, the switch is on, and data can flow from the A port to the B port, or vice versa. When /EN is high, the switch is open, and the high-impedance state exists between the two ports.

APPLICATIONS INFORMATION

Memory Interface

- Solution for multiple memory devices on a bus

Bus Isolation

- Ability to electrically isolate a device, or banks of devices, from memory bus or ADC output when not needed
- Enables bank switching for redundancy or device failure
- Provides cold-sparing capability without the need for actual cold-sparing buffers

Redundancy

- Allows multiple non cold-spare devices to be present on a bus

Supports Analog Applications

- In voltage range: 3.0 to 3.6V or 4.5 to 5.5V
- Signal isolation: -60dB
- Bandwidth (3dB): 500 MHz

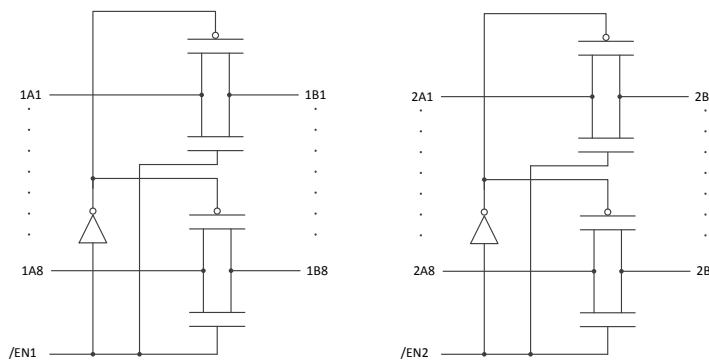


Figure 1. UT54BS16245 Block Diagram

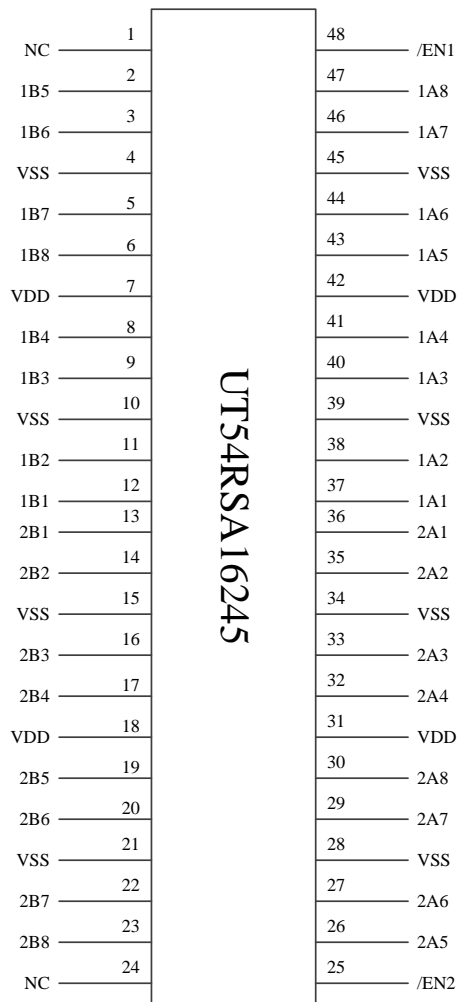


Figure 2. UT54BS16245 Pinout

PIN DESCRIPTION

Pin No.	Name	Description
26, 27, 29, 30, 32, 33, 35, 36, 37, 38, 40, 41, 43, 44, 46, 47	nAn	Port A pins
2, 3, 5, 6, 8, 9, 11, 12, 13, 14, 16, 17, 19, 20, 22, 23	nBn	Port B pins
25, 48	/ENn	Active LOW enable pin
4, 10, 15, 21, 28, 34, 39, 45	VSS	Ground Pin
7, 18, 31, 42	VDD	Supply Pin, +3.3V –or- +5.0V
1, 24	NC	No Connect (electrically not connected to die)

TRUTH TABLE

INPUT (/EN)	Function
L	A port to B port -or- B port to A port
H	DISCONNECT

ABSOLUTE MAXIMUM RATINGS ¹

Symbol	Parameter	MIN	MAX	Unit
V_{DD}^2	Positive Output Supply Voltage	-0.5	7.2	V
V_I^2	Voltage on an Input pin during operation		$V_{DD}+0.3V$	V
I_{CCC}	Continuous DC Channel Current		65	mA
P_D^3	Maximum package power dissipation permitted at $T_C=125^{\circ}C$		1.6	W
T_J	Junction Temperature		+150	$^{\circ}C$
Θ_{JC}	Thermal resistance, junction-to-case		15	$^{\circ}C/W$
T_{STG}	Storage Temperature	-65	+150	$^{\circ}C$
ESD	ESD protection (Human Body Model) Class 2		2000	V

Notes:

1. Permanent device damage may occur if absolute maximum ratings are exceeded. Functional operation should be restricted to recommended operating conditions. Exposure to absolute maximum rating conditions for extended periods may affect device reliability and performance.
2. All voltages referenced to VSS
3. Per MIL-STD-883, method 1012.1, section 3.4.1, $PD=(T_j(max) - T_c(max)) / \Theta_{jc}$

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	LIMIT	Unit
V_{DD}^1	Positive Output Supply Voltage	3.0 to 3.6 or 4.5 to 5.5	V
V_{IN}^1	Input Voltage on any pin	0.0 to V_{DD}	V
T_C	Case Temperature Range	-55 to +125	$^{\circ}C$
t_R	Rise time	>5	ns
t_F	Fall time	>5	ns
I_{CCC}	Continuous DC Channel Current	60	mA

Notes:

1. All voltages referenced to VSS

OPERATIONAL ENVIROMENT

PARAMETER	LIMIT	UNITS
Total Ionizing Dose (TID)	3.0E5	rad(Si)
Single Event Latchup (SEL)	>100	MeV-cm ² /mg

DC CHARACTERISTICS^{*,1}

($V_{DD} = 5.0V \pm 0.5V, 3.3V \pm 0.3V, -55^{\circ}C < T_C < +125^{\circ}C$); Unless otherwise noted, Tc is per the temperature range ordered

Symbol	Parameter	Condition	MIN	MAX	Unit
V_{IH}	High level input voltage	$V_{DD}=3.6V, 5.5V$	$0.7*V_{DD}$		V
V_{IL}	Low level input voltage	$V_{DD}=3.0V, 4.5V$		$0.3*V_{DD}$	V
I_{ID}	Leakage current digital	$V_{DD}= MAX;$ $V_I = V_{DD} \text{ or } V_{SS}$	-1	1	μA
I_{IA}	Leakage current analog	$V_{DD}= MAX;$ $V_I = V_{DD} \text{ or } V_{SS}$	-3	3	μA
I_{DD}	Active Supply Current	$V_{DD}=3.6V, 5.5V$		0.5	mA/MHz
I_{DDQ}	Quiescent Supply Current	$V_{DD}= MAX;$ $I_O = 0mA;$ $V_I = V_{DD} \text{ or } V_{SS}$		15	μA
C_I	Input Capacitance (/EN)	$V_I = V_{DD} \text{ or } V_{SS}$		5	pF
$C_{IO(OFF)}$	I/O Capacitance when device OFF	$V_{DD} = MAX$ $V_O = V_{DD} \text{ or } V_{SS}$ $V_I = V_{DD}/2$ $/EN = V_{DD}$		5	pF
$C_{IO(ON)}$	I/O Capacitance when device ON	$V_{DD} = MAX$ $V_O = \text{open}$ $V_I = V_{DD}/2$ $/EN = 0V$		16	pF
$R_{ONL}^{2,3}$	Resistance through switch	$V_{DD}= 4.5V$ $V_I = V_{SS}$	$I_O = 30mA$ $I_O = 15mA$	10 13	Ω
		$V_{DD}= 3.0V$ $V_I = V_{SS}$	$I_O = 30mA$ $I_O = 15mA$	10 13	Ω
$R_{ONM}^{2,3}$	Resistance through switch	$V_{DD}=4.5V$ $V_I = V_{DD}/2$	$I_O = -30mA$ $I_O = -15mA$	10 13	Ω
		$V_{DD}=3.0V$ $V_I = V_{DD}/2$	$I_O = -30mA$ $I_O = -15mA$	10 13	Ω

Symbol	Parameter	Condition		MIN	MAX	Unit
$R_{ONH}^{1,2}$	Resistance through switch	$V_{DD}=4.5V$ $V_I = V_{DD}$	$I_O = -30mA$ $I_O = -15mA$		10 13	Ω
		$V_{DD}= 3.0V$ $V_I = V_{DD}$	$I_O = -30mA$ $I_O = -15mA$		10 13	Ω
$R_{ON(Flat)}^{1,2}$	Switch On Resistance	$V_{DD}=3.0V,4.5V$ $V_I = V_{DD}$	$I_O = -30mA$ $I_O = -15mA$		5 6	Ω

Notes:

- * For devices procured with a total ionizing dose tolerance guarantee, the post-irradiation performance is guaranteed at 25°C per MIL-STD-883 Method 1019, Condition A up to the maximum TID level procured.
- 1. Measured by the voltage drop between the A and B terminals at the indicated current through the switch. On-state resistance is determined by the lowest voltage of the two (A or B) terminals.
- 2. Guaranteed by design.

AC CHARACTERISTICS ^{*,1}

($V_{DD} = 5.0V \pm 0.5V$, $-55^{\circ}C < T_C < +125^{\circ}C$); Unless otherwise noted, T_C is per the temperature range ordered

Symbol	From (INPUT)	To (OUTPUT)	Cond.	MIN	MAX	Unit
t_{PD30}^1	A or B	B or A	$I_I = +/-30mA$		500	ps
t_{PD15}^1	A or B	B or A	$I_I = +/-15mA$		650	ps
t_{EN}	/EN= V_{SS}	A or B		1	5	ns
t_{DIS}	/EN= V_{DD}	A or B		1	7	ns

($V_{DD} = 3.3V \pm 0.3V$, $-55^{\circ}C < T_C < +125^{\circ}C$); Unless otherwise noted, T_C is per the temperature range ordered

Symbol	From (INPUT)	To (OUTPUT)	Cond.	MIN	MAX	Unit
t_{PD30}^1	A or B	B or A	$I_I = +/-30mA$		1	ns
t_{PD15}^1	A or B	B or A	$I_I = +/-15mA$		1.3	ns
t_{EN}	/EN= V_{SS}	A or B		1	7	ns
t_{DIS}	/EN= V_{DD}	A or B		1	8	ns

Notes:

* For devices procured with a total ionizing dose tolerance guarantee, the post-irradiation performance is guaranteed at 25°C per MIL-STD-883 Method 1019, Condition A up to the maximum TID level procured.

1. The propagation delay through the channel is based upon the RC time constant of the channel resistance and switch ON capacitance, 11 Ω and 17pF.

Symbol	Parameter	Condition	MIN	MAX	Unit
X_{TALK}^1	Cross talk between channels $V_{DD} = 5.0V$	$RL = 50\Omega$, $CL = 50pF$, $f = 1MHz$, $V_{IN1} = 1V_{RMS}$ Centered at $V_{DD}/2$		-60	dB
X_{TALK}^1	Cross talk between channels $V_{DD} = 3.3V$	$RL = 50\Omega$, $CL = 50pF$, $f = 1MHz$, $V_{IN1} = 1V_{RMS}$ Centered at $V_{DD}/2$		-60	dB
I_{SOFF}^1	Off Isolation	$RL = 50\Omega$, $CL = 50pF$, $f = 1MHz$, $V_{IN1} = 1V_{RMS}$ Centered at $V_{DD}/2$		-60	dB

Notes:

1. Guaranteed by design.

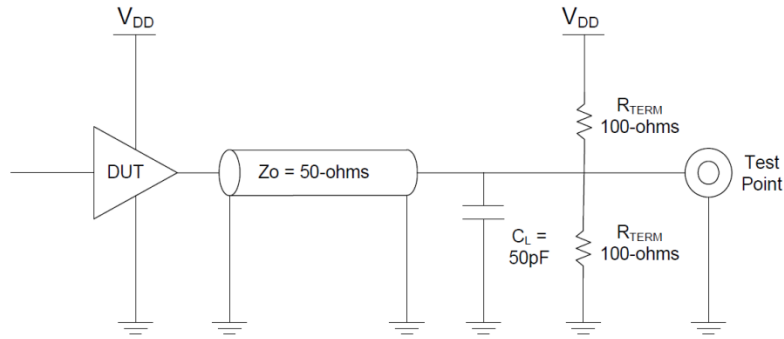


Figure 3. Output Test Load Circuit

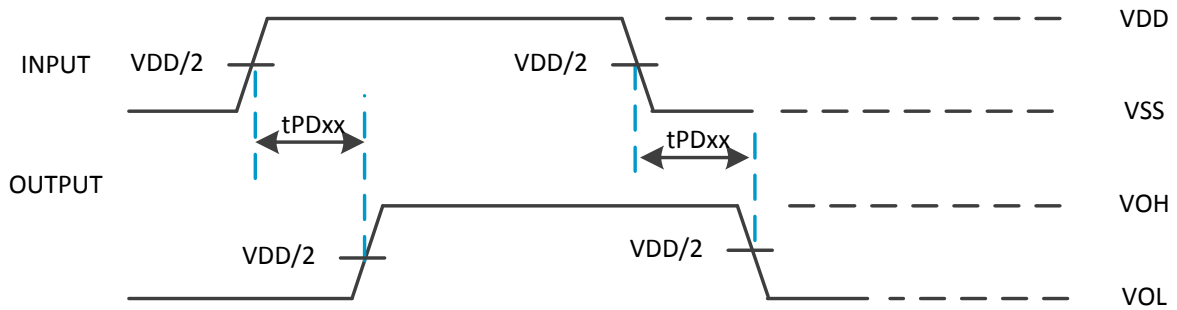


Figure 4. Propagation Waveform

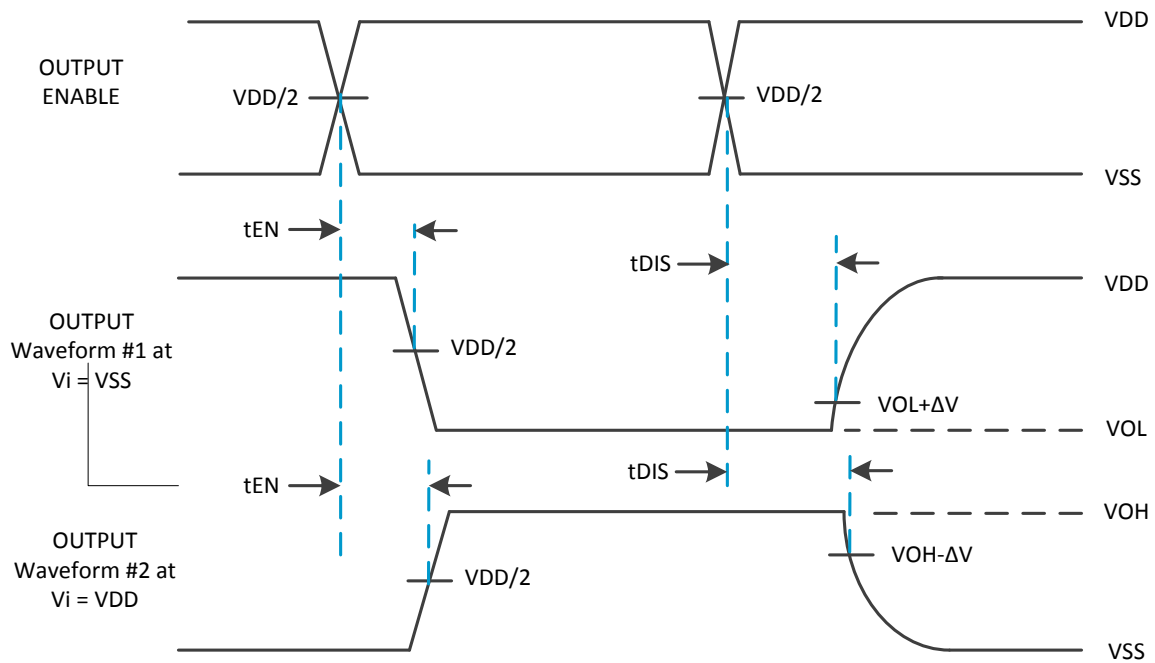


Figure 5. Propagation Waveform

PACKAGING

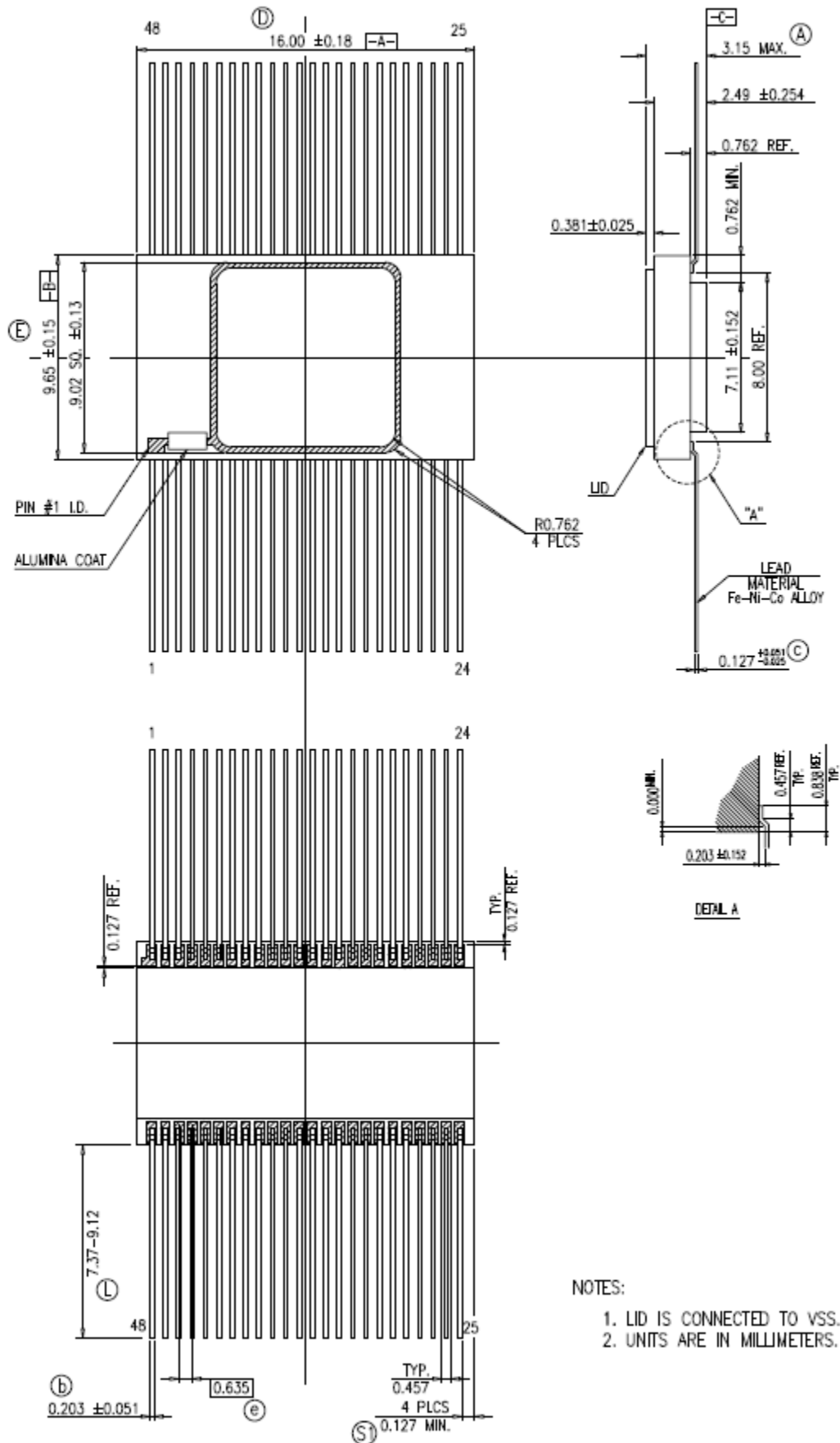
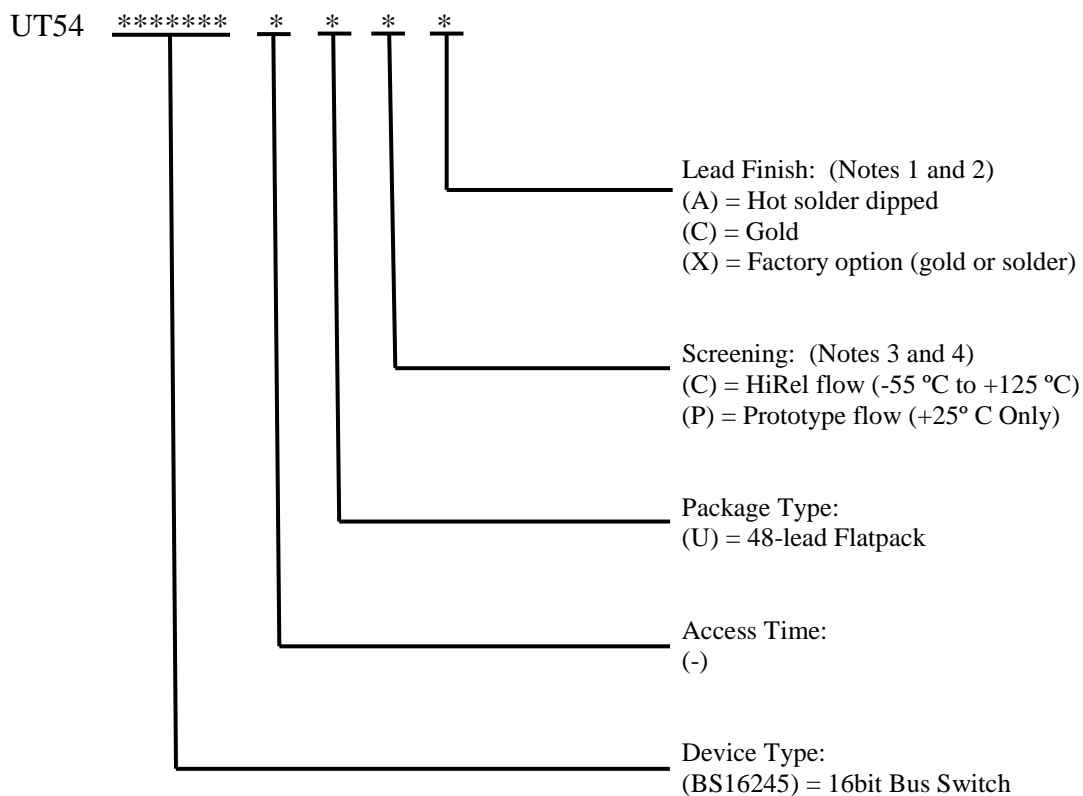


Figure 6. 48-lead Ceramic Flatpack

ORDERING INFORMATION

UT54BS16245 16bit Bus Switch Analog:

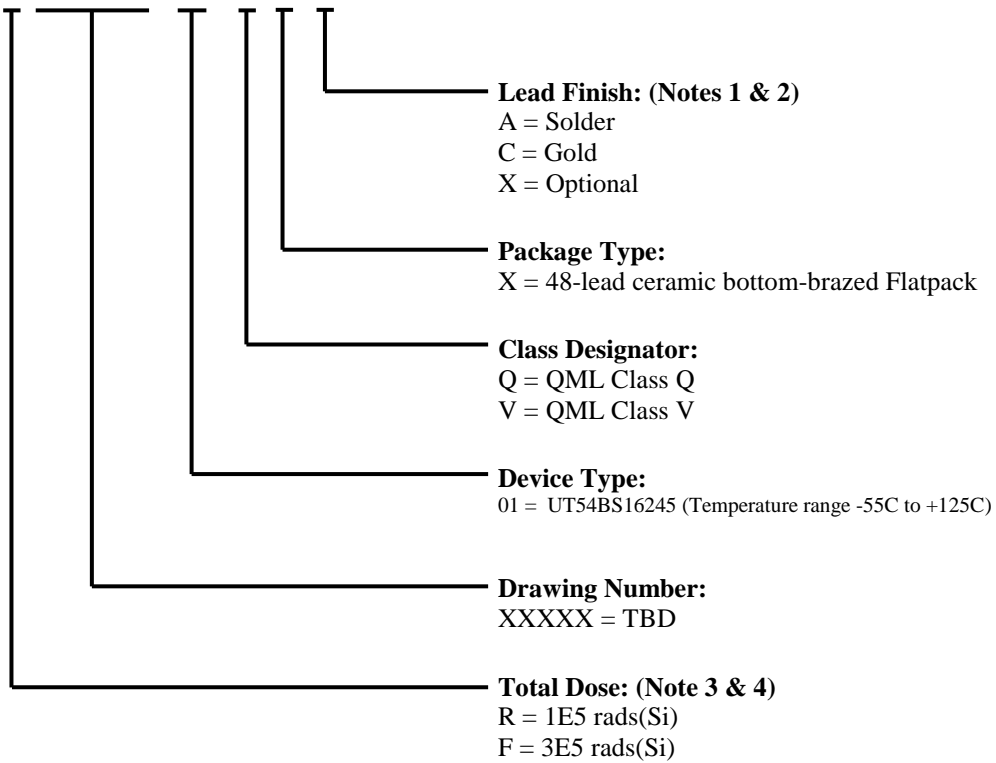


Notes:

1. Lead finish (A,C, or X) must be specified.
2. If an "X" is specified when ordering, then the part marking will match the lead finish and will be either "A" (solder) or "C" (gold).
3. Prototype flow per Aeroflex Manufacturing Flows Document. Tested at 25 ° C only. Lead finish is GOLD ONLY. Radiation neither tested nor guaranteed.
4. HiRel Temperature Range flow per Aeroflex Manufacturing Flows Document. Devices are tested at -55°C, room temp, and 125°C. Radiation neither tested nor guaranteed.

UT54BS16245 Bus Switch Analog SMD:

5962 - XXXXX ** * * *



Notes:

1. Lead finish (A,C, or X) must be specified.
2. If an "X" is specified when ordering, part marking will match the lead finish and will be either "A" (solder) or "C" (gold).

Aeroflex Colorado Springs - Datasheet Definition

Advanced Datasheet - Product In Development

Preliminary Datasheet - Shipping Prototype

Datasheet - Shipping QML & Reduced Hi – Rel

**This product is controlled for export under the U.S. Department of Commerce (DoC).
A license may be required prior to the export of this product from the United States.**

COLORADO
Toll Free: 800-645-8862
Fax: 719-594-8468

INTERNATIONAL
Tel: 805-778-9229
Fax: 805-778-1980

NORTHEAST
Tel: 603-888-3975
Fax: 603-888-4585

SE AND MID-ATLANTIC
Tel: 321-951-4164
Fax: 321-951-4254

WEST COAST
Tel: 949-362-2260
Fax: 949-362-2266

CENTRAL
Tel: 719-594-8017
Fax: 719-594-8468

www.aeroflex.com info-ams@aeroflex.com

Aeroflex Colorado Springs, Inc., reserves the right to make changes to any products and services herein at any time without notice. Consult Aeroflex or an authorized sales representative to verify that the information in this data sheet is current before using this product. Aeroflex does not assume any responsibility or liability arising out of the application or use of any product or service described herein, except as expressly agreed to in writing by Aeroflex; nor does the purchase, lease, or use of a product or service from Aeroflex convey a license under any patent rights, copyrights, trademark rights, or any other of the intellectual rights of Aeroflex or of third parties.



Our passion for performance is defined by three attributes represented by these three icons: solution-minded, performance-driven and customer-focused